# MSKSEMI 美森科













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LM321

产品手册





#### 产品简介

LM321 是一款单路输出的低功耗差分式运算放大器,可以单电源或双电源供电。具有较高的开环增益、 内部补偿、高共模范围和良好的温度稳定性,以及具有输出短路保护的特点。可应用于传感器的放大电路、 直流放大模块,音频放大电路和传统的运算放大电路中

### 产品特点

- 单电源电压范围: 3V~36V
- 双电源电压范围: ±18V
- 单位增益带宽:可达 1.2MHZ
- 输出短路保护
- 低功耗: 0.5mA @ V+=5V
- 封装形式: SOT-23-5

### 产品用途

- 传感器信号放大器
- 直流増益
- 音频放大器
- 其它应用领域

## 封装形式和管脚

封装形式	管脚定义	丝印	
SOT-23-5	+IN 1 5 V <sup>+</sup> V <sup>-</sup> 2 4 OUTPUT	A63A	

SOT23-5 管脚序号	管脚定义	功能说明
1	IN+	正相输入
2	V-	电源负
3	IN-	反相输入
4	OUTPUT	输出
5	V+	电源正

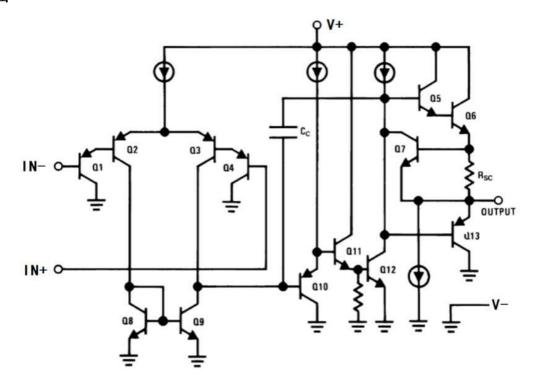


### 极限参数

项目	符号	极限值 <sup>(1)</sup>	单位
单电源供电电压	V+	40	V
双电源供电电压	Vs	±20	V
差分输入电压 (2)	$V_{ m IDR}$	±40	V
共模输入电压	$V_{ m ICR}$	-0.3∼40V	V
输出短路时间	$t_{\mathrm{sc}}$	连续	
耗散功率	PD	300	mW
工作温度	TA	0-70	${\mathbb C}$
储存温度	Ts	-65-150	${\mathbb C}$
焊接温度	Tw	260, 10s	${\mathbb C}$

- 注: (1) 极限值是指无论在任何条件下都不能超过的极限值。如果达到此极限值,将有可能造成产品劣化等物理性损伤;同时在接近极限参数下,不能保证芯片可以正常工作。
  - (2) 输入 IN+与 IN-之间的电压差。

# 等效原理图





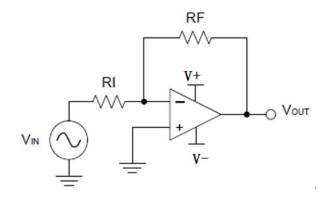
**直流电学特性** (T<sub>A</sub>=25℃, V+ =5V, V− =GND 除非特别指定)

项目	符号	测试条件		最小值	典型值	最大值	单位
输入失调电压	VIO	V+ =5V to MAX, V <sub>IC</sub> =V <sub>ICR</sub> (min), VO=1.4V		_	5	_	mV
输入失调电流	IIO	VO = 1.4 V		_	10	50	nA
偏置电流	IBIAS	VO = 1.4 V		_	50	250	nA
共模输入电压	Vicr	V+=5V to 36V		V-	_	V+ -1.5V	V
开环电压增益	Aol	V+=15V, VO=1V to 11	V, RL≥2k Ω		100	_	V/mV
共模抑制比	CMRR	V+=5V to MAX, V <sub>IC</sub> =VICR (min)		_	80	_	dB
单位增益带宽	GBWP			_	1.2	_	MHZ
电源电压抑制比Pssr	ΔVvdd/ΔVio	V+=5V to MAX, f=20kHz		_	90	_	dB
	VOH	V+ =15V, V <sub>ID</sub> =1V	Iout =-50uA	_	13. 6	_	V
   輸出高电平电压			Iout =-1mA	_	13. 5	-	V
柳山内屯「屯压	VOII		Iout =-5mA	_	13. 4	_	V
		V+ =28V	RL=2k		26	ı	V
	VOL	V+ =15V, V <sub>ID</sub> =-1V	Iout =50uA	_	0. 1	-	V
输出低电平电压			Iout =1mA	_	0. 7	-	V
相山以电   电压			Iout =5mA	_	1.0	-	V
		V+ =28V	RL=2k	_	0.85	-	V
电源工作电流		V+ =5V, V0=1/2V+, No load		_	0. 5	-	mA
巴 <i>你</i> 工作电机	Icc	V+ =36, V0=1/2V+, No load		_	0.8	-	mA
单电源工作电压	V+	V- =0V (GND)		3	_	36	V
双电源工作电压	VS	V+, V-		-18	_	+18	V



#### 典型应用

#### 1、线路图



#### 2、设计要求

必须选择大于输入电压范围和输出范围的电源电压。

例如,将信号源 VIN 从±0.5 V 放大到±1.8V。将电源设置为±5 V 足以适应此应用要求。

#### 3、设计过程

根据公式(1)计算放大倍数(增益) Av

$$A_V = -VO/VIN$$
 ----(1)

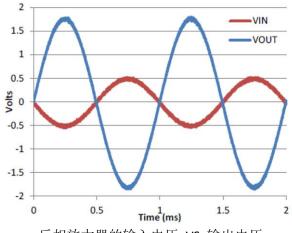
$$A_V = -VO/VIN = -1.8/0.5 = -3.6$$

一旦确定了所需的增益  $A_V$ ,就要为 RI 或 RF 电阻选择一个值。根据运放的电特性及功耗的需要,可选择  $1k\,\Omega$ - $100k\,\Omega$ 范围内的值。本例将选择 RI= $10\,k\,\Omega$ ,则 RF= $36k\,\Omega$ 。这由方程式 2 确定。

$$A_{V} = -RF/RI -----(2)$$

$$RF = -A_V * RI = 3.6*10 = 36 k \Omega$$

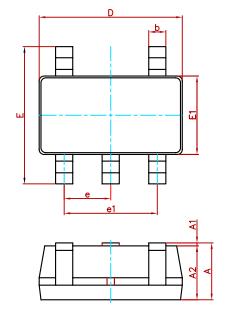
#### 4、应用曲线图

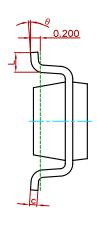


反相放大器的输入电压 VS 输出电压



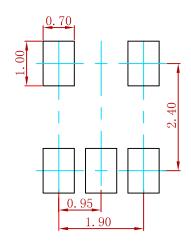
# 封装信息





Cumbal	Dimensions In Millimeters		Dimension	ns In Inches
Symbol	Min.	Max.	Min.	Max.
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	2.650	2.950	0.104	0.116
E1	1.500	1.700	0.059	0.067
е	0.950(BSC)		0.037	7(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

# 焊盘布局



- Note:
  1.Controlling dimension:in millimeters.
  2.General tolerance:± 0.05mm.
  3.The pad layout is for reference purposes only.

# 订购信息

P/N	PKG	QTY
LM321	SOT-23-5	3000



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